



Features

- BVCEO > 20V
- Ic = 2.5A Continuous Collector Current
- $R_{CE(sat)} = 50m\Omega$ for a low equivalent On-Resistance
- 625mW Power dissipation
- hFE characterized up to 6A for high current gain hold up
- Complementary NPN type: FMMT718Q
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- The FMMT618Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

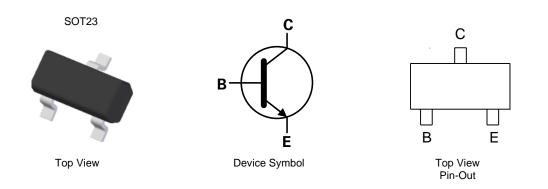
20V NPN LOW SATURATION TRANSISTOR IN SOT23

Mechanical Data

- Package: SOT23
- Package Material: molded plastic, "Green" molding compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 3
- Weight 0.008 grams (Approximate)

Applications

- DC-DC Modules
- Gate Driver
- LED Driver



Ordering Information (Note 4)

Product	Package	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FMMT618QTA	SOT23	618	7	8	3,000

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

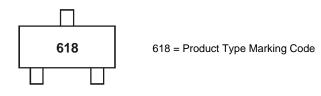
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

Notes:





Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	Vcbo	20	V
Collector-Emitter Voltage	VCEO	20	V
Emitter-Base Voltage	VEBO	7	V
Continuous Collector Current	lc	2.5	А
Peak Pulse Current	Ісм	6	А
Base Current	lB	500	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

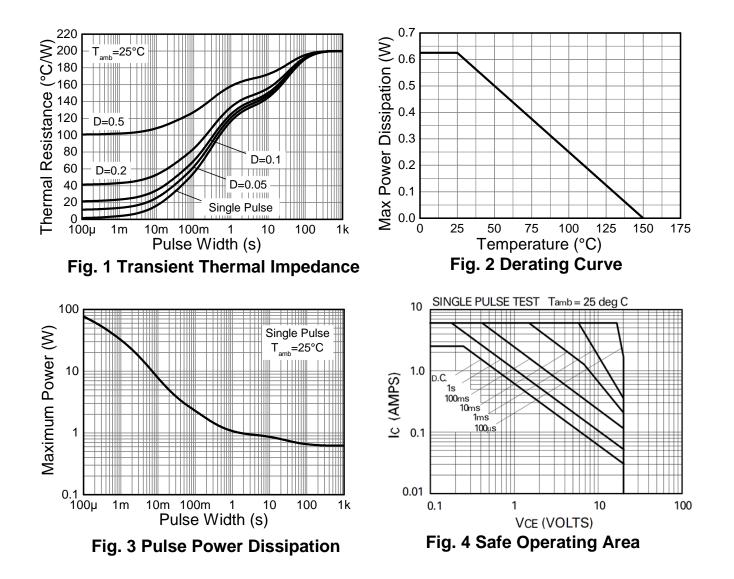
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	625	mW
Power Dissipation (Note 6)	PD	806	mW
Thermal Resistance, Junction to Ambient (Note 5)	Reja	200	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	Reja	155	°C/W
Thermal Resistance, Junction to Leads (Note 7)	Rejl	194	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

5. For a device surface mounted on 25mm x 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured Notes: when operating in a steady-state condition.

6. Same as note 6, except the device is measured at $t \le 5$ sec. 7. Thermal resistance from junction to solder-point (at the end of the collector lead).



Thermal Characteristics and Derating information





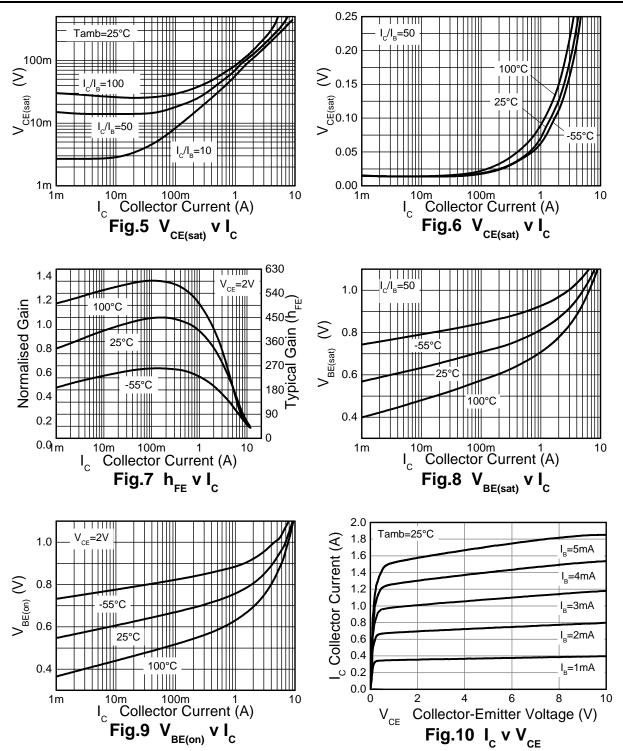
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	20	100	-	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 8)	BVCEO	20	27	-	V	Ic = 10mA
Emitter-Base Breakdown Voltage	BVEBO	7	8.3	-	V	I _E = 100μA
Collector Cut-off Current	Ісво	-	-	100	nA	V _{CB} =20V
Emitter Cut-off Current	IEBO	-	-	100	nA	$V_{EB} = 4V$
Collector Emitter Cut-off Current	ICES	-	-	100	nA	V _{CES} =20V
Static Forward Current Transfer Ratio (Note 8)	hfe	200 300 200 100	400 450 340 150	- - -	-	Ic = 10mA, VcE = 2V Ic = 200mA, VcE = 2V Ic = 2A, VcE = 2V Ic = 6A, VcE = 2V
Collector-Emitter Saturation Voltage (Note 8)	VCE(sat)		8 70 130	15 150 200	mV	I _C =0.1A, I _B = 10mA I _C =1A, I _B = 10mA I _C =2.5A, I _B = 50mA
Base-Emitter Saturation Voltage (Note 8)	VBE(sat)	-	0.89	1	V	Ic =2.5A, I _B = 50mA
Base-Emitter Saturation Voltage (Note 8)	VBE(on)	-	0.83	1	V	Ic =2.5A, Vce = 2V
Transition Frequency	fт	100	140	-	MHz	$I_{C} = 50 \text{mA}, V_{CE} = 10 \text{V},$ f=100MHz
Collector Output Capacitance	Cobo	-	23	30	pF	$V_{CB} = 10V$, f=1MHz
Turn-On Time	ton	-	170	-	ns	$V_{CC} = 10V, I_{C} = 1A,$
Turn-Off Time	toff	-	400	-	ns	$I_{B1} = -I_{B2} = 10 \text{mA}$

Note: 8. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%



Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)





Тур

1.00

0.05

0.45

0.10

3.00

2.42

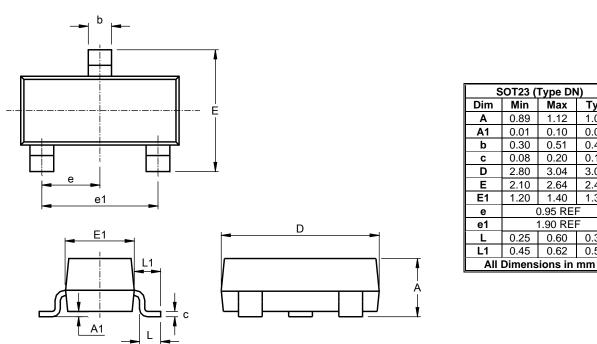
1.37

0.30

0.54

Package Outline Dimensions

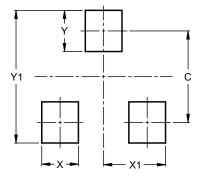
Please see http://www.diodes.com/package-outlines.html for the latest version.



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.





Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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